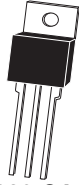


CS220-8B
CS220-8D
CS220-8M
CS220-8N

SILICON CONTROLLED RECTIFIER
8.0 AMP, 200 THRU 800 VOLTS



TO-220 CASE

CentralTM
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CS220-8B series type is an Epoxy Molded Silicon Controlled Rectifier designed for sensing circuit applications and control systems.

MARKING CODE: FULL PART NUMBER

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	CS220 -8B	CS220 -8D	CS220 -8M	CS220 -8N	UNITS
Peak Repetitive Off-State Voltage	V_{DRM}, V_{RRM}	200	400	600	800	V
RMS On-State Current ($T_C=90^\circ\text{C}$)	$I_T(\text{RMS})$			8.0		A
Peak One Cycle Surge ($t=10\text{ms}$)	I_{TSM}			60		A
I^2t Value for Fusing ($t=10\text{ms}$)	I^2t			18		A^2s
Peak Gate Power ($t_p=10\mu\text{s}$)	P_{GM}			40		W
Average Gate Power Dissipation	$P_G(\text{AV})$			1.0		W
Peak Forward Gate Current ($t_p=10\mu\text{s}$)	I_{FGM}			4.0		A
Peak Forward Gate Voltage ($t_p=10\mu\text{s}$)	V_{FGM}			16		V
Peak Reverse Gate Voltage ($t_p=10\mu\text{s}$)	V_{RGM}			5.0		V
Critical Rate of Rise of On-State Current	di/dt			50		$\text{A}/\mu\text{s}$
Storage Temperature	T_{stg}		-40 to +150			$^\circ\text{C}$
Junction Temperature	T_J		-40 to +125			$^\circ\text{C}$
Thermal Resistance	θ_{JA}			60		$^\circ\text{C}/\text{W}$
Thermal Resistance	θ_{JC}			2.5		$^\circ\text{C}/\text{W}$

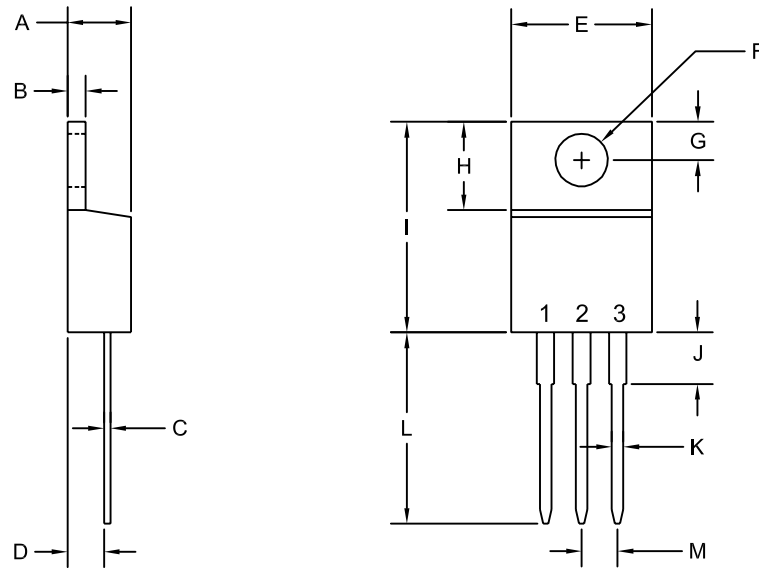
ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{DRM}, I_{RRM}	Rated V_{DRM}, V_{RRM}			10	μA
I_{DRM}, I_{RRM}	Rated $V_{DRM}, V_{RRM}, T_C=125^\circ\text{C}$			2.0	mA
I_{GT}	$V_D=12\text{V}, R_L=10\Omega$		3.0	15	mA
I_H	$I_T=100\text{mA}$		7.3	20	mA
V_{GT}	$V_D=12\text{V}, R_L=10\Omega$		0.9	1.5	V
V_{TM}	$I_{TM}=16\text{A}, t_p=380\mu\text{s}$		1.3	1.8	V
dv/dt	$V_D=2/3 V_{DRM}, T_C=125^\circ\text{C}$	200			$\text{V}/\mu\text{s}$

R3 (24-September 2004)

SILICON CONTROLLED RECTIFIER
8.0 AMP, 200 THRU 800 VOLTS

TO-220 CASE - MECHANICAL OUTLINE



R2

LEAD CODE:

- 1) CATHODE
- 2) ANODE
- 3) GATE

NOTE: TAB IS COMMON
TO PIN 2 (ANODE)

MARKING CODE:

FULL PART NUMBER

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.170	0.190	4.31	4.82
B	0.045	0.055	1.15	1.39
C	0.013	0.026	0.33	0.65
D	0.083	0.107	2.10	2.72
E	0.394	0.417	10.01	10.60
F (DIA)	0.140	0.157	3.55	4.00
G	0.100	0.118	2.54	3.00
H	0.230	0.270	5.85	6.85
I	0.560	0.625	14.23	15.87
J	-	0.250	-	6.35
K	0.025	0.038	0.64	0.96
L	0.500	0.579	12.70	14.70
M	0.090	0.110	2.29	2.79

TO-220 (REV: R2)

R3 (24-September 2004)